## NSN 5962-01-184-6648

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View Online at https://aerobasegroup.com/nsn/5962-01-184-6648

Body Length:
1.290 inches
Body Width:
Between 0.500 inches and 0.610 inches
Body Height:
0.210 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+125.0 degrees celsius
Features Provided:
Programmable and ultraviolet erasable and monolithic
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
N-type metal oxide-semiconductor logic
Input Circuit Pattern:
14 input
Case Outline Source And Designator:
D-3 mil-m-38510
Current Rating Per Characteristic:
150.00 milliamperes supply
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
6.0 volts power source
Time Rating Per Chacteristic:
450.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Prom
Memory Capacity:
4k x 8
Test Data Document:
96906-mil-std-883  standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
24 printed circuit
Shelf Life:

N/a

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**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

Fiig:

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